PHOTODIODE

PDI-40-P10-4G-K

OVERVIEW
PDI-40-P10-4G-K is the InGaAs PIN photodiode coupled to an optical fiber and packaged into a hermetic case.

MAIN FEATURES
- Maximum optical input power: 10 mW
- Bandwidth: 4 GHz
- Typical responsivity: 1.0 A/W at 1550 nm
- Package types: coaxial with or without bracket
- Low back reflection, return loss RL > 50 dB
- Low dark current 0.02 nA

APPLICATIONS
- Optical fiber communication systems

ORDERING INFORMATION


Optical matching
- R50: back reflection -50 dB (SM1 and SM3 fiber)
- RM: back reflection -30 dB, optical matching, +5% higher responsivity

Case type
- U: compact coaxial
- B: compact coaxial with double-sided bracket

Fiber type
- SM1: G.657.A1, furcation tubing ∅0.9 mm
- SM3: G.657.B3, furcation tubing ∅0.9 mm
- Other type: on request

Connector type
- FU: FC/UPC
- FA: FC/APC
- N: no connector
- Other type: on request

Fiber length
- 0.5: 500+/−50 mm
- 1.0: 1000+/−100 mm
- Other length: on request

Version 20.1

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# PHOTODIODE

## PDI-40-P10-4G-K

### ABSOLUTE MAXIMUM RATINGS

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Value</th>
<th>Unit</th>
<th>Conditions</th>
</tr>
</thead>
<tbody>
<tr>
<td>Maximum optical input power</td>
<td>$P_{\text{max}}$</td>
<td>10 mW</td>
<td></td>
</tr>
<tr>
<td>Reverse voltage</td>
<td>$V_R$</td>
<td>20 V</td>
<td></td>
</tr>
<tr>
<td>Forward current</td>
<td>$I_F$</td>
<td>10 mA</td>
<td></td>
</tr>
<tr>
<td>Operating temperature</td>
<td>$T_{\text{op}}$</td>
<td>-40 ÷ +85 °C</td>
<td></td>
</tr>
<tr>
<td>Storage temperature</td>
<td>$T_{\text{stg}}$</td>
<td>-40 ÷ +85 °C</td>
<td></td>
</tr>
<tr>
<td>Soldering temperature</td>
<td>$T_{\text{sold}}$</td>
<td>260 °C</td>
<td>Max. 5 seconds</td>
</tr>
</tbody>
</table>

### ELECTRICAL-OPTICAL CHARACTERISTICS (T = 25 °C)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
<th>Conditions</th>
</tr>
</thead>
<tbody>
<tr>
<td>Responsivity</td>
<td>RM</td>
<td>R</td>
<td>1.00</td>
<td>1.10</td>
<td>A/W $\lambda = 1550$ nm</td>
</tr>
<tr>
<td></td>
<td>R50</td>
<td></td>
<td>0.95</td>
<td>1.05</td>
<td>$\lambda = 1550$ nm</td>
</tr>
<tr>
<td>Return loss</td>
<td>RL</td>
<td>45</td>
<td>50</td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td></td>
<td>R50</td>
<td></td>
<td>25</td>
<td>30</td>
<td></td>
</tr>
<tr>
<td>Operating voltage</td>
<td>$V_{\text{op}}$</td>
<td>3</td>
<td>5</td>
<td></td>
<td>$V_R = 3$ V</td>
</tr>
<tr>
<td>Dark current</td>
<td>$I_d$</td>
<td>0.02</td>
<td>0.08</td>
<td>nA</td>
<td>$V_R = 3$ V, f = 1 MHz</td>
</tr>
<tr>
<td>Total capacitance</td>
<td>$C_t$</td>
<td>0.55</td>
<td>0.80</td>
<td>pF</td>
<td>$V_R = 3$ V</td>
</tr>
<tr>
<td>Chip capacitance</td>
<td>$C_{\text{chip}}$</td>
<td>0.35</td>
<td>0.50</td>
<td>pF</td>
<td>$V_R = 3$ V, f = 1 MHz</td>
</tr>
<tr>
<td>Bandwidth</td>
<td>BW</td>
<td>4</td>
<td></td>
<td>GHz</td>
<td>$P_{i} = -10$ dBm, $V_{G} = 3$ V, $R_L = 50$ Ω, Small signal modulation</td>
</tr>
</tbody>
</table>
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CHARACTERISTICS (T = 25 °C)
PHOTODIODE

PDI-40-P10-4G-K

PACKAGE TYPE AND ELECTRICAL PINOUT

PACKAGE U

SIDE VIEW

BACK VIEW

PINOUT

Connector FC/UPC, FC/APC, no connector, or by request

Fiber length 500+/−50, 1000+/−100, or by request

PACKAGE B

SIDE VIEW

BACK VIEW

PINOUT

Connector FC/UPC, FC/APC, no connector, or by request

Fiber length 500+/−50, 1000+/−100, or by request
PDI-40-P10-4G-K

Characteristics, data, materials and structures specified in this datasheet are subject to change without notice. Please refer to the latest specification before use of the products.

Safety and handling cautions
1. Avoid smashing and burning of the module. Avoid storing and using the module in conditions where water, organic solvents or aggressive acids or bases may contact the module or where there is a possibility of exposure to corrosive gases, explosive gases, dust, salinity or other harsh conditions. The module should be disposed as special industrial waste.
2. Exceeding absolute maximal ratings even for a short time can cause permanent damage of the module.
3. The module is sensitive to and can be broken by ESD (static electricity).

Conflict Minerals Policy Statement
LasersCom LLC achieves business objectives and customer needs with social responsibility. We do not support or contribute to the violence and human rights violations associated with the mining of conflict minerals coming from Conflict Regions according to US “Dodd-Frank Act”. When possible, our suppliers’ conflict mineral statements are reviewed. We do not directly purchase Conflict Minerals from any source and do not knowingly procure any parts and products containing Conflict Minerals from Conflict Regions.

RoHS Compliance Statement
Restriction of Hazardous Substances (RoHS) directive (Directive 2011/65/EC amended with Directive (EU) 2015/863) is the directive aimed at reducing the harmful environmental impact of waste electrical equipment by restricting the use of known dangerous substances. Based on information received from our supply sources, LasersCom LLC hereby states that the banned substances listed in the RoHS directive are not found in the parts and materials used above the threshold level listed other than exceptions approved by the European Commission.

REACH Compliance Statement
Registration, Evaluation, Authorisation and Restriction of Chemicals (REACH) is a European Union regulation 1907/2006/EC that addresses the production and use of chemical substances, and their potential impacts on human health and the environment. Based on information received from our supply sources, LasersCom LLC hereby states compliance of the parts and materials used in manufacturing to REACH regulation. LasersCom LLC does not manufacture or import any substances or preparations as defined under REACH.